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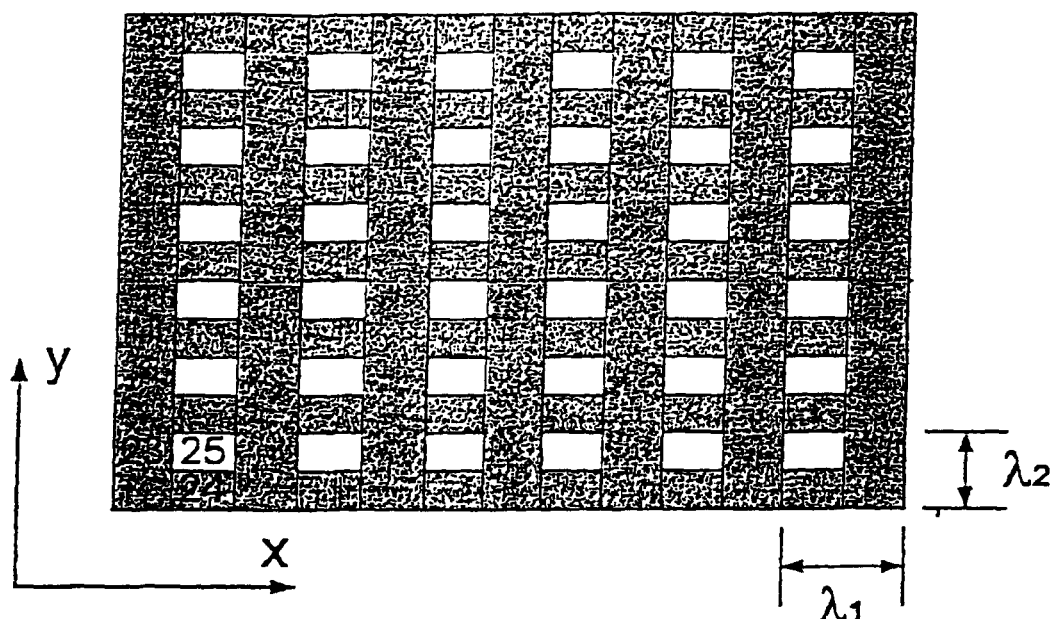
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(54) Title: SURFACE ACOUSTIC WAVE DEVICE



(57) Abstract: A surface acoustic wave device which can generate surface acoustic waves in at least two directions. The device includes a piezoelectric layer, an elastic substrate and an electrode layer which includes two arrays 23 and 24 of linear electrodes with gap regions 25 located between the electrodes. Alternatively, the electrode layer may be patterned as an array of concentric annular strips for the generation of annular surface acoustic waves.



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